





FMMT494

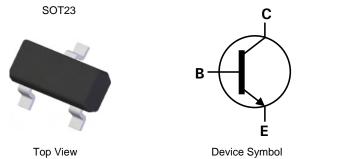
### 120V NPN SILICON PLANAR MEDIUM POWER TRANSISTOR IN SOT23

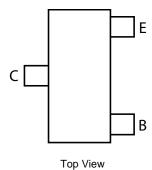
### **Feature**

- BV<sub>CEO</sub> > 120V
- I<sub>C</sub> = 1A Continuous Collector Current
- I<sub>CM</sub> = 2A Peak Pulse Current
- 500mW Power Dissipation
- h<sub>FE</sub> characterised up to 1A for high current gain hold up
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP capable (Note 4)

## **Mechanical Data**

- Case: SOT23
- Case Material: molded plastic, "Green" molding compound
- UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 63
- Weight 0.008 grams (approximate)





Pin-Out

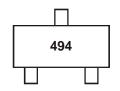
## Ordering Information (Notes 4 & 5)

Part Number	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
FMMT494TA	AEC-Q101	494	7	8	3,000
FMMT494TC	AEC-Q101	494	13	8	10,000
FMMT494QTA	Automotive	494	7	8	3,000
FMMT494QTC	Automotive	494	13	8	10,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen and Antimony free, "Green" and Lead-Free.
- 3. Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified.
- 5. For packaging details, go to our website at http://www.diodes.com

## **Marking Information**



494 = Product Type Marking Code





Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	140	V
Collector-Emitter Voltage	V <sub>CEO</sub>	120	V
Emitter-Base Voltage	V <sub>EBO</sub>	7	V
Continuous Collector Current	Ic	1	А
Peak Pulse Current	I <sub>CM</sub>	2	Α
Base Current	I <sub>B</sub>	200	mA

# Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 6)	P <sub>D</sub>	500	mW
Thermal Resistance, Junction to Ambient (Note 6)	$R_{ hetaJA}$	250	°C/W
Thermal Resistance, Junction to Lead (Note 7)	$R_{ heta JL}$	197	°C/W
Operating and Storage Temperature Range	T <sub>J,</sub> T <sub>STG</sub>	-55 to +150	°C

## ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	≥ 400	V	С

Notes:

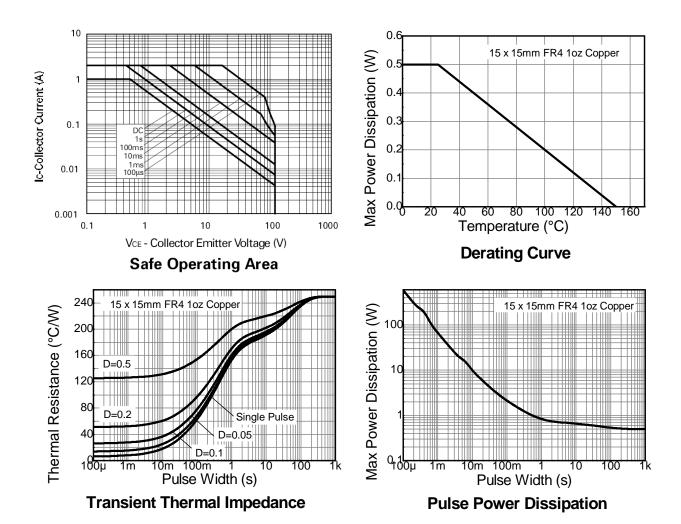
<sup>6.</sup> For a device surface mounted on 15mm X 15mm FR4 PCB with high coverage of single sided 1 oz copper, in still air conditions; the device is measured when operating in a steady-state condition.

7. Thermal resistance from junction to solder-point (at the end of the collector lead).

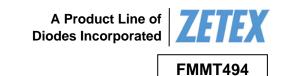
8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



## **Thermal Characteristics and Derating Information**







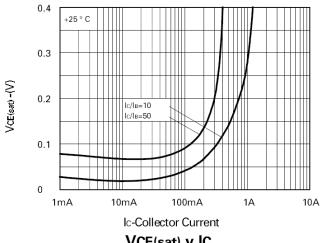
# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

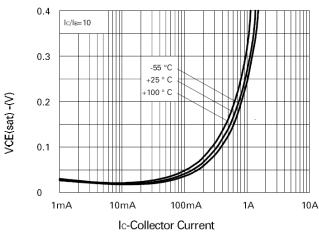
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	140	_	_	V	$I_{C} = 100 \mu A$
Collector-Emitter Breakdown Voltage (Note 9)	BV <sub>CEO</sub>	120	_	_	V	I <sub>C</sub> = 1mA
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	7	_	_	V	$I_E = 100\mu A$
Collector Cutoff Current	I <sub>CBO</sub>	_	_	100	nA	V <sub>CB</sub> = 120V
Emitter Cutoff Current	I <sub>EBO</sub>	_	_	100	nA	V <sub>EB</sub> = 5V
Collector Emitter Cutoff Current	I <sub>CES</sub>	_	_	100	nA	V <sub>CE</sub> = 120V
		100	_	_	_	$I_C = 1mA$ , $V_{CE} = 10V$
Static Forward Current Transfer Ratio (Note 9)	h <sub>FE</sub>	100	_	300		$I_C = 250 \text{mA}, V_{CE} = 10 \text{V}$
Static Forward Current Transfer Ratio (Note 9)		60	_	_		I <sub>C</sub> = 500mA, V <sub>CE</sub> = 10V
		20	_	_		I <sub>C</sub> = 1A, V <sub>CE</sub> = 10V
Collector-Emitter Saturation Voltage (Note 9)	V <sub>CE(sat)</sub>	_	_	200	mV	$I_C = 250 \text{mA}, I_B = 25 \text{mA}$
Collector-Emitter Saturation voltage (Note 9)		_	_	300	IIIV	$I_C = 500 \text{mA}, I_B = 50 \text{mA}$
Base-Emitter Turn-On Voltage(Note 9)	$V_{BE(on)}$	_	_	1.0	V	$I_C = 500 \text{mA}, V_{CE} = 10 \text{V}$
Base-Emitter Saturation Voltage(Note 9)	V <sub>BE(sat)</sub>	_	_	1.1	V	$I_C = 500 \text{mA}, I_B = 50 \text{mA}$
Output Capacitance	$C_{obo}$	_	_	10	pF	$V_{CB} = 10V$ , $f = 1MHz$
Transition Frequency	f⊤	100	_	_	MHz	$V_{CE} = 50V, I_{C} = 10mA,$ f = 100MHz

Notes: 9. Measured under pulsed conditions. Pulse width  $\leq$  300 $\mu$ s. Duty cycle  $\leq$  2%.

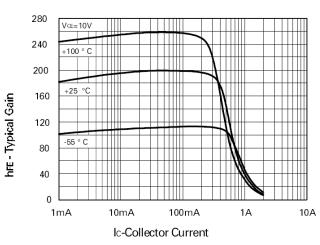


Typical Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

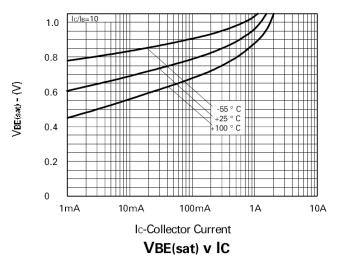




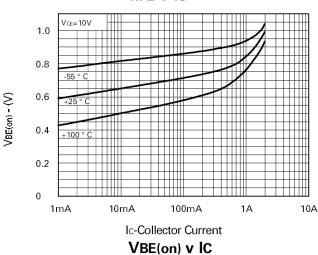
## VCE(sat) v IC







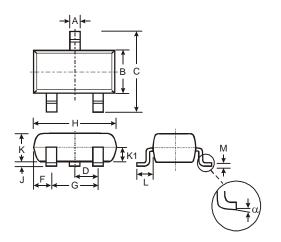
### hFE V IC





# **Package Outline Dimensions**

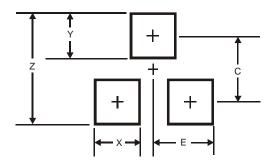
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



SOT23					
Dim	Min	Max	Тур		
Α	0.37	0.51	0.40		
В	1.20	1.40	1.30		
С	2.30	2.50	2.40		
D	0.89	1.03	0.915		
F	0.45	0.60	0.535		
G	1.78	2.05	1.83		
Н	2.80	3.00	2.90		
J	0.013	0.10	0.05		
K	0.903	1.10	1.00		
<b>K</b> 1	-	-	0.400		
L	0.45	0.61	0.55		
M	0.085	0.18	0.11		
α	0°	8°	-		
All	All Dimensions in mm				

# **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)		
Z	2.9		
Х	0.8		
Υ	0.9		
С	2.0		
E	1.35		





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